



Description

The XPX40N012LL uses advanced trench technology and design to provide excellent $R_{DS(ON)}$ with low gate charge. It can be used in a wide variety of applications.

General Features

- High density cell design for ultra low $R_{DS(on)}$
- Fully characterized avalanche voltage and current
- Good stability and uniformity with high E_{AS}
- Excellent package for good heat dissipation

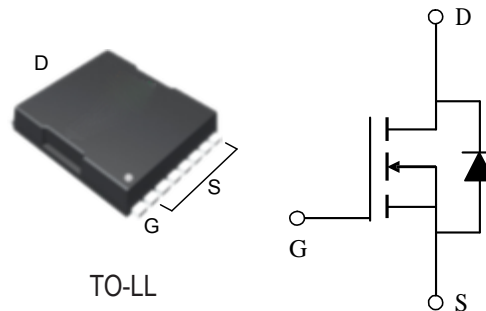
Application

- PWM
- Load Switching

$V_{DS} = 40V, I_D = 200A$

$R_{DS(ON)} = 1.0m\Omega$ (typ) @ $V_{GS} = 10V$

$R_{DS(ON)} = 1.6m\Omega$ (typ) @ $V_{GS} = 4.5V$



Package Marking and Ordering Information

Device	Pack	Marking	Qty(PCS)
XPX40N012LL	TOLL	40N012 XXXX YYYY	

Absolute Maximum Ratings ($T_C = 25^\circ C$ unless otherwise noted)

Symbol	Parameter	Rating	Units
V_{DS}	Drain-Source Voltage	40	V
V_{GS}	Gate-Source Voltage	± 20	V
$I_D @ T_C = 25^\circ C$	Continuous Drain Current, $V_{GS} @ 10V^1$	200	A
$I_D @ T_C = 100^\circ C$	Continuous Drain Current, $V_{GS} @ 10V^1$	180	A
IDM	Pulsed Drain Current ²	400	A
EAS	Single Pulse Avalanche Energy ³	500	mJ
IAS	Avalanche Current	45	A
$P_D @ T_C = 25^\circ C$	Total Power Dissipation ⁴	375	W
TSTG	Storage Temperature Range	-55 to 150	$^\circ C$
T_J	Operating Junction Temperature Range	-55 to 150	$^\circ C$
$R_{\theta JA}$	Thermal Resistance Junction-Ambient ¹	52	$^\circ C/W$
$R_{\theta JC}$	Thermal Resistance Junction-Case ¹	0.85	$^\circ C/W$

Electrical Characteristics ($T_A = 25^\circ\text{C}$ unless otherwise noted)

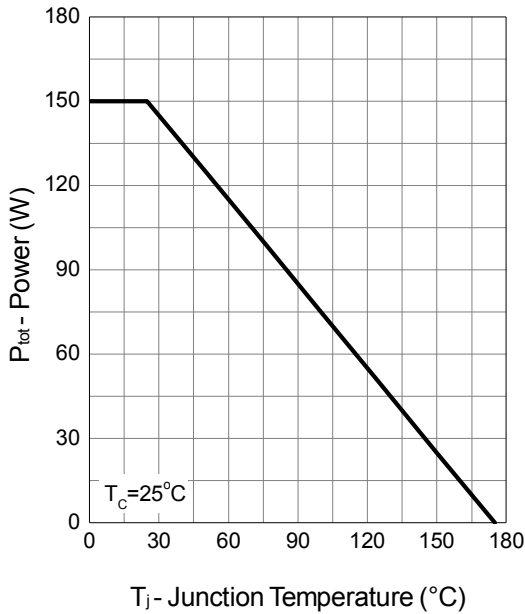
Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
Static Characteristics						
BV_{DSS}	Drain-Source Breakdown Voltage	$V_{GS}=0V, I_{DS}=250\mu A$	40	-	-	V
I_{DSS}	Zero Gate Voltage Drain Current	$V_{DS}=32V, V_{GS}=0V$ $T_J=85^\circ\text{C}$	-	-	1	μA
			-	-	30	
$V_{GS(th)}$	Gate Threshold Voltage	$V_{DS}=V_{GS}, I_{DS}=250\mu A$	1.5	2	2.5	V
I_{GSS}	Gate Leakage Current	$V_{GS}=\pm 20V, V_{DS}=0V$		-	± 100	nA
$R_{DS(ON)}$	Drain-Source On-state Resistance	$V_{GS}=10V, I_{DS}=25A$ $T_J=125^\circ\text{C}$	-	1	1.3	m Ω
			-	2.4	-	
		$V_{GS}=4.5V, I_{DS}=25A$	-	1.6	1.9	
Gfs	Forward Transconductance	$V_{DS}=5V, I_{DS}=20A$	-	3.5	-	S
Diode Characteristics						
V_{SD}^e	Diode Forward Voltage	$I_{SD}=20A, V_{GS}=0V$	-	0.78	1.1	V
t_{rr}	Reverse Recovery Time	$I_{SD}=25A, di_{SD}/dt=100A/\mu s$ $V_{dd}=20V$	-	61	-	ns
t_a	Charge Time		-	31	-	
t_b	Discharge Time		-	30	-	
Q_{rr}	Reverse Recovery Charge		-	67	-	
Dynamic Characteristics^f						
R_G	Gate Resistance	$V_{GS}=0V, V_{DS}=0V, F=1\text{MHz}$	0.6	0.9	2	Ω
C_{iss}	Input Capacitance	$V_{GS}=0V,$ $V_{DS}=20V,$ Frequency=1.0MHz	-	8988	-	pF
C_{oss}	Output Capacitance		-	2000	-	
C_{rss}	Reverse Transfer Capacitance		-	175	-	
$t_{d(ON)}$	Turn-on Delay Time	$V_{DD}=20V, R_L=20\Omega,$ $I_{DS}=1A, V_{GEN}=10V,$ $R_G=1\Omega$	-	18.8	-	ns
t_r	Turn-on Rise Time		-	9.8	-	
$t_{d(OFF)}$	Turn-off Delay Time		-	50	-	
t_f	Turn-off Fall Time		-	90.8	-	
Gate Charge Characteristics^f						
Q_g	Total Gate Charge	$V_{DS}=20V, V_{GS}=10V,$ $I_{DS}=25A$	-	88.98	-	nC
Q_{gth}	Threshold Gate Charge		-	15.84	-	
Q_{gs}	Gate-Source Charge		-	24.75	-	
Q_{gd}	Gate-Drain Charge		-	15.63	-	

Note e¹ Pulse test ; pulse width $\leq 300\mu s$, duty cycle $\leq 2\%$.

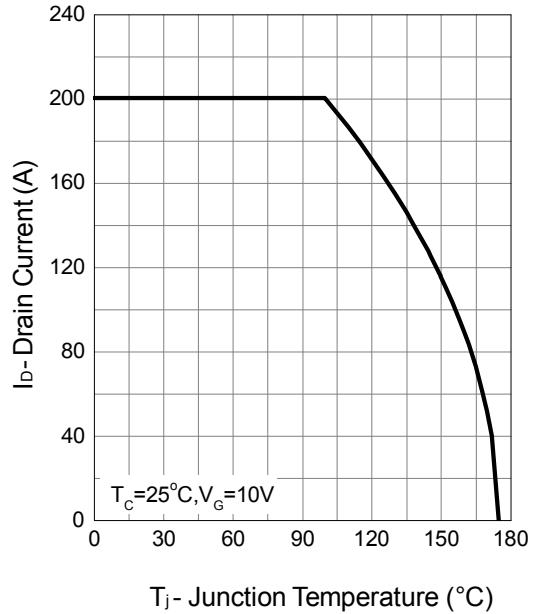
Note f¹ Guaranteed by design, not subject to production testing.

Typical Operating Characteristics

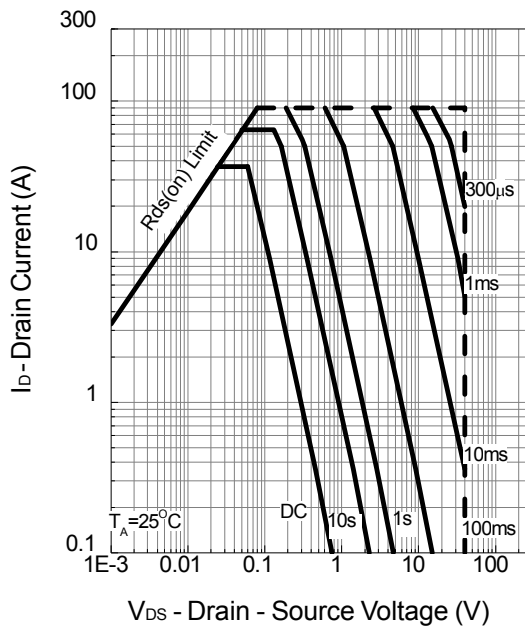
Power Dissipation



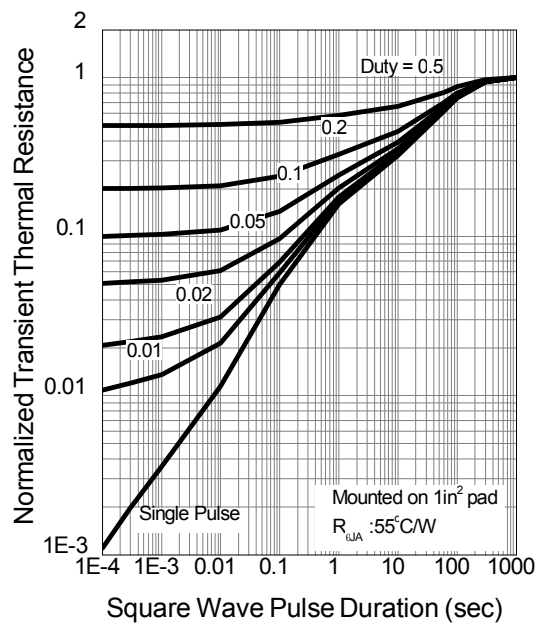
Drain Current



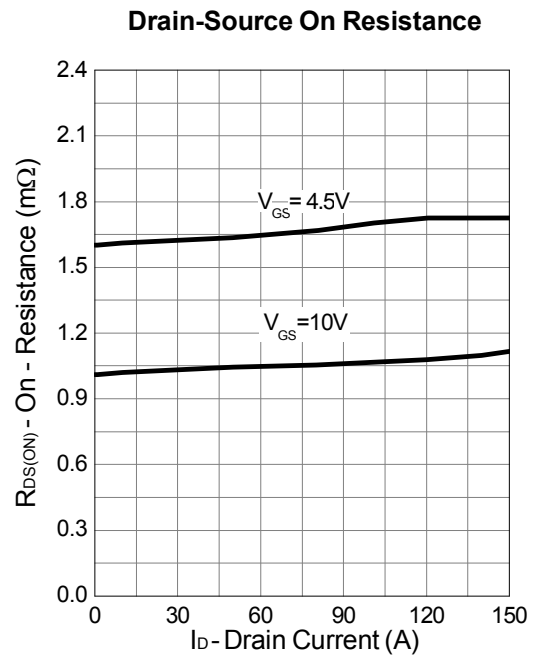
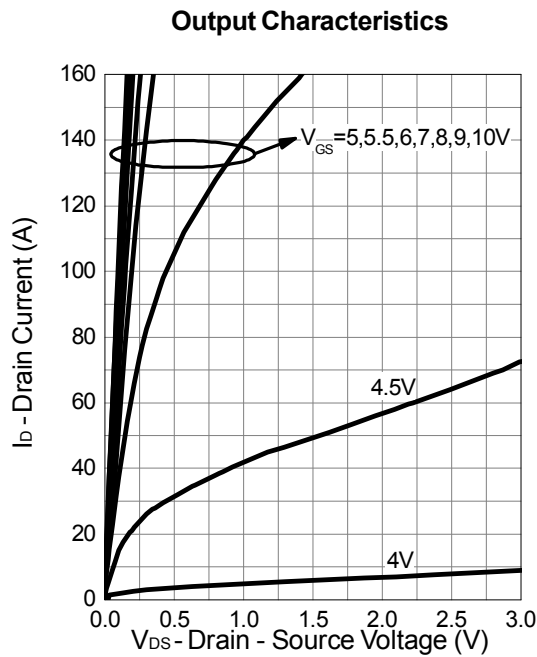
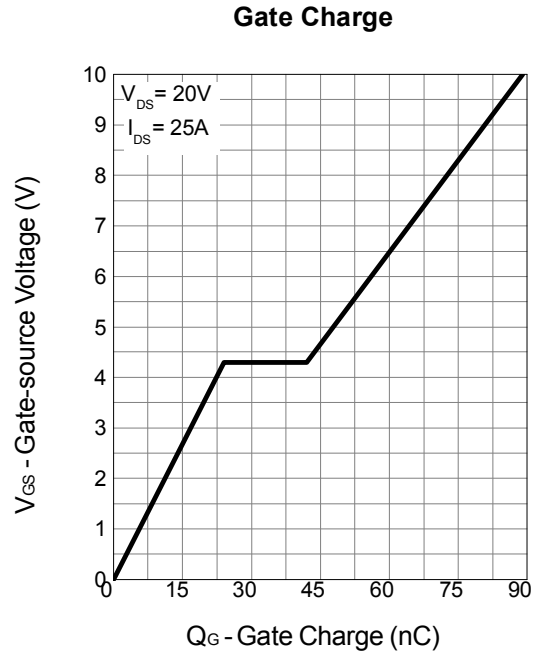
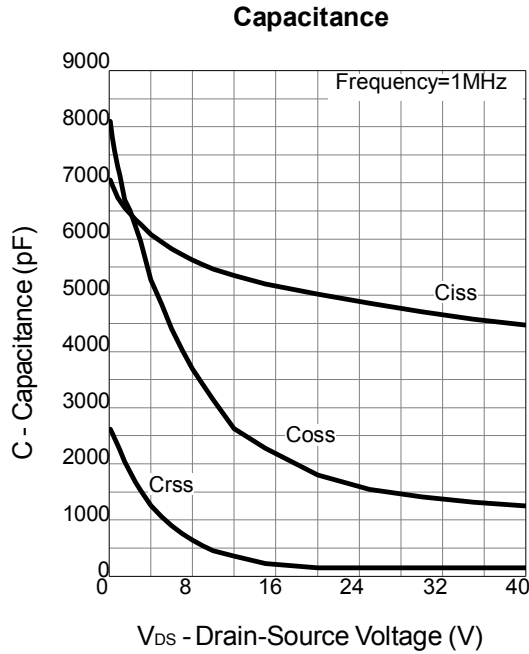
Safe Operation Area



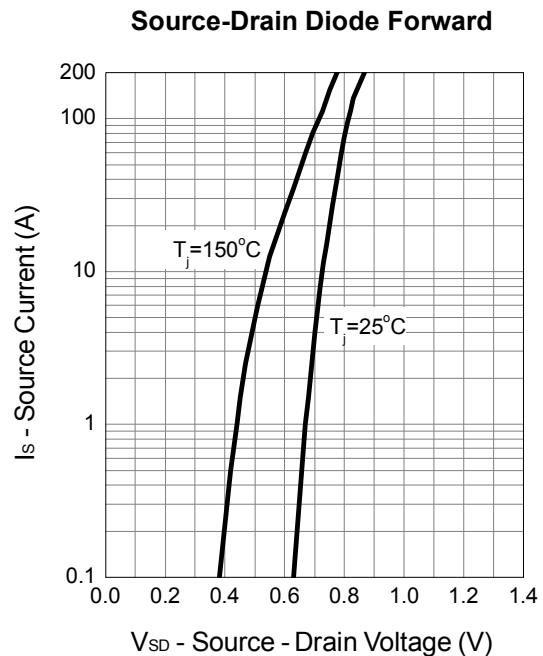
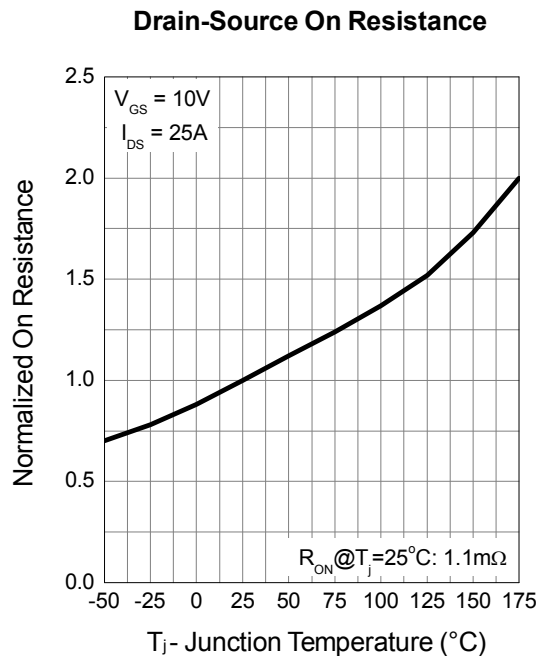
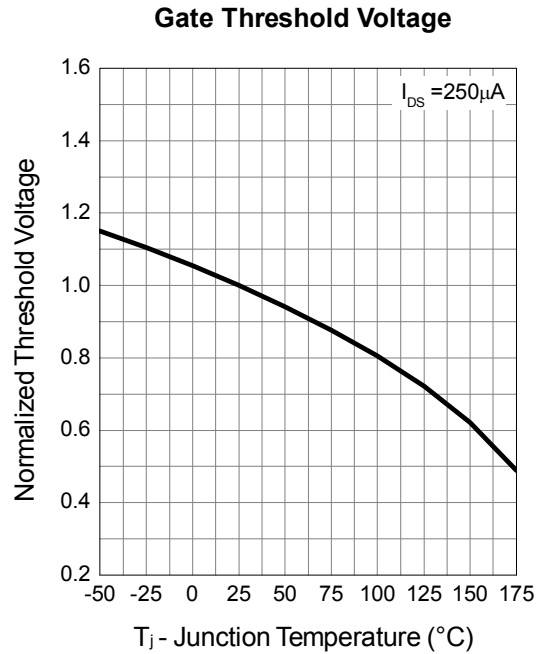
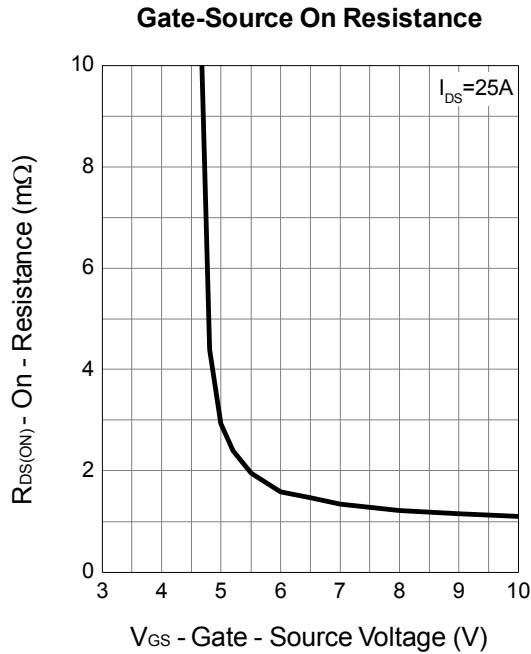
Thermal Transient Impedance



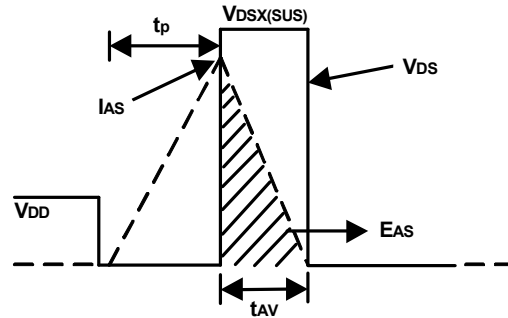
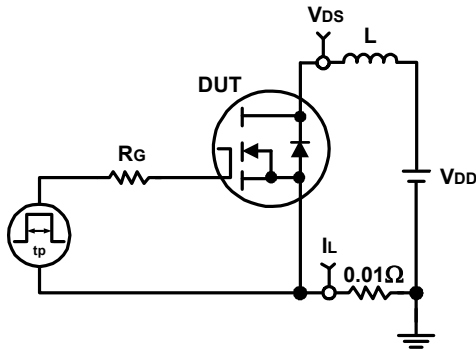
Typical Operating Characteristics (Cont.)



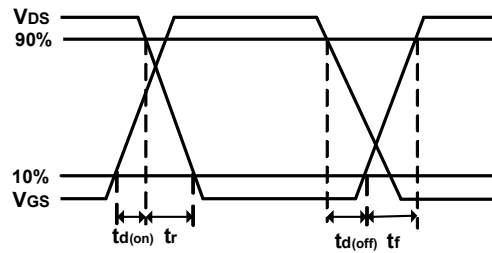
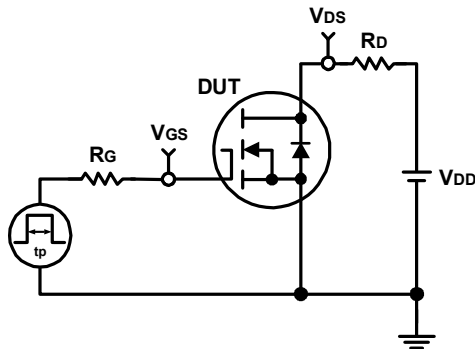
Typical Operating Characteristics (Cont.)



Avalanche Test Circuit and Waveforms

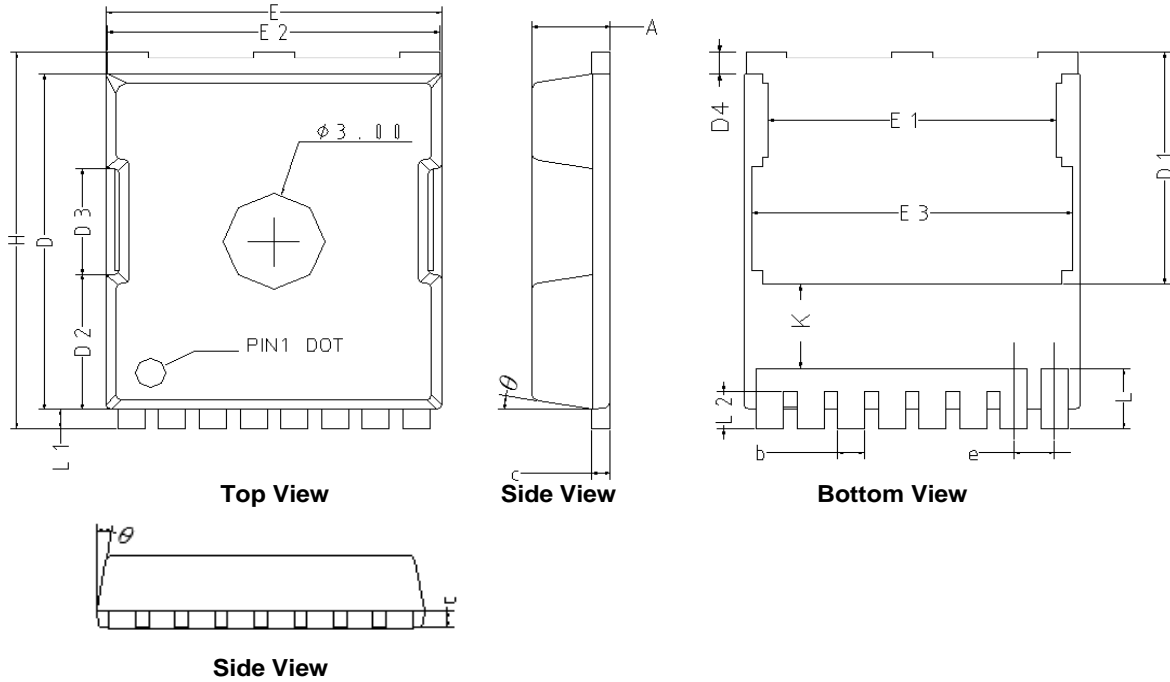


Switching Time Test Circuit and Waveforms



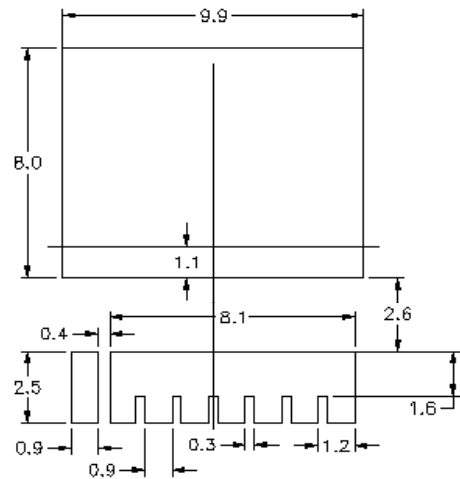
Package Information

TOLL



SYMBOLS	TO-LL			
	MILLIMETERS		INCHES	
	MIN.	MAX.	MIN.	MAX.
A	2.20	2.40	0.087	0.094
b	0.70	0.90	0.028	0.035
c	0.40	0.60	0.016	0.024
D	10.23	10.63	0.403	0.419
D1	7.05	7.45	0.278	0.293
D2	3.98	4.38	0.157	0.172
D3	3.10	3.50	0.122	0.138
D4	0.50	0.90	0.020	0.035
E	9.70	10.10	0.382	0.398
E1	8.30	8.70	0.327	0.343
E2	9.60	10.00	0.378	0.394
E3	9.26	9.66	0.365	0.380
H	11.53	11.93	0.454	0.470
e	1.2 BSC		0.0472 BSC	
K	2.43	2.83	0.096	0.111
L	1.65	2.05	0.065	0.081
L1	0.40	0.80	0.016	0.031
L2	0.95	1.35	0.037	0.053
θ	6°	10°	6°	10°

RECOMMENDED LAND PATTERN



UNIT: mm

Flow (wave) soldering (solder dipping)

Product	Peak Temperature	Dipping Time
Pb device	245°C ±5°C	5sec ±1sec
Pb-Free device	260°C +0/-5°C	5sec ±1sec



This integrated circuit can be damaged by ESD. UniverChip Corporation recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedure can cause damage. ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

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